NSN 5961-01-443-9687

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-443-9687 **Inclosure Material:** Plastic **Mounting Method:** Terminal **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 125.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Tape and reeled, 1500 per reel **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli

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